

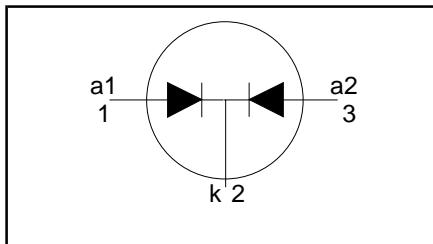
Rectifier diodes
Schottky barrier

PBYR6045WT series

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 40 \text{ V/} 45 \text{ V}$$

$$I_{F(AV)} = 60 \text{ A}$$

$$V_F \leq 0.58 \text{ V}$$

GENERAL DESCRIPTION

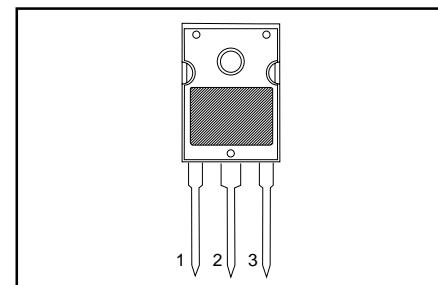
Dual, common cathode schottky rectifier diodes in a plastic envelope. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR6045WT series is supplied in the conventional leaded SOT429 (TO247) package.

PINNING

PIN	DESCRIPTION
1	anode 1 (a)
2	cathode (k)
3	anode 2 (a)
tab	cathode

SOT429 (TO247)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V_{RRM}	Peak repetitive reverse voltage	PBYR60	-	40WT	45WT	V
V_{RWM}	Working peak reverse voltage		-	40	45	V
V_R	Continuous reverse voltage	$T_{mb} \leq 109 \text{ }^\circ\text{C}$	-	40	45	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting)	square wave; $\delta = 0.5$; $T_{mb} \leq 105 \text{ }^\circ\text{C}$	-	60		A
I_{FRM}	Repetitive peak forward current per diode	square wave; $\delta = 0.5$; $T_{mb} \leq 105 \text{ }^\circ\text{C}$	-	60		A
I_{FSM}	Non-repetitive peak forward current per diode	$t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ sinusoidal; $T_j = 125 \text{ }^\circ\text{C}$ prior to surge; with reapply $V_{RRM(max)}$ pulse width and repetition rate limited by $T_{j\max}$	- -	400 435	A A	
I_{RRM}	Peak repetitive reverse surge current per diode		-	2	A	
T_j	Operating junction temperature		-	150	$^\circ\text{C}$	
T_{stg}	Storage temperature		-65	150	$^\circ\text{C}$	

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-mb}$	Thermal resistance junction to mounting base	per diode	-	-	1	K/W
$R_{th j-a}$	Thermal resistance junction to ambient	both diodes in free air	-	-	0.75	K/W
			-	45	-	K/W

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ELECTRICAL CHARACTERISTICS $T_j = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage per diode	$I_F = 30 \text{ A}; T_j = 125^\circ\text{C}$ $I_F = 60 \text{ A}; T_j = 125^\circ\text{C}$	-	0.51	0.58	V
I_R	Reverse current per diode	$I_F = 30 \text{ A}$ $I_F = 60 \text{ A}$ $V_R = V_{RWM}$ $V_R = V_{RWM}; T_j = 100^\circ\text{C}$	-	0.7	0.75	V
C_d	Junction capacitance	$V_R = 5 \text{ V}; f = 1 \text{ MHz}, T_j = 25^\circ\text{C} \text{ to } 125^\circ\text{C}$	-	0.54	0.61	V
			-	0.69	0.76	V
			-	0.3	5	mA
			-	30	90	mA
			-	1000	-	pF

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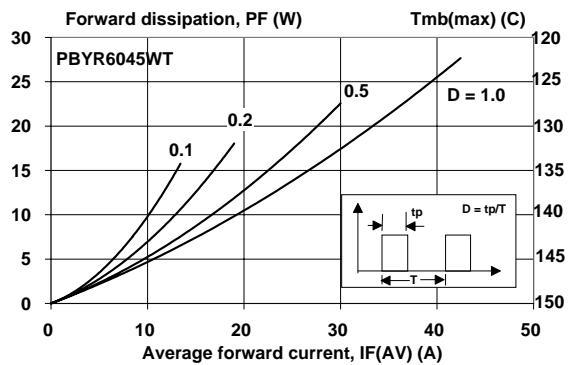


Fig.1. Maximum forward dissipation $P_F = f(IF_{(AV)})$ per diode; square current waveform where $IF_{(AV)} = IF_{(RMS)} \times \sqrt{D}$.

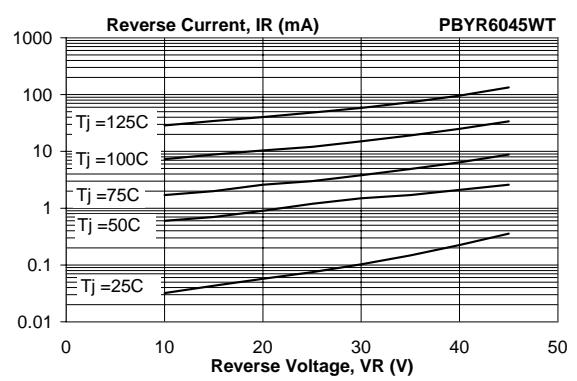


Fig.4. Typical reverse leakage current per diode; $I_R = f(V_R)$; parameter T_j

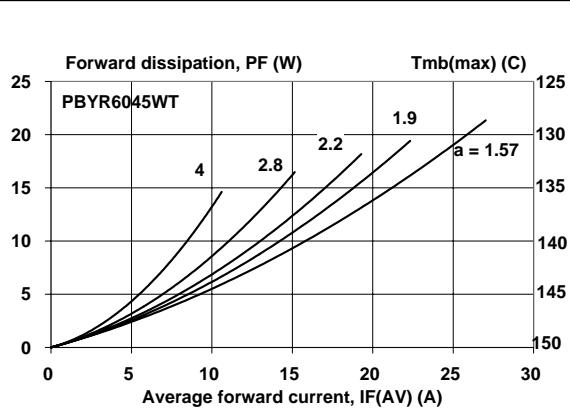


Fig.2. Maximum forward dissipation $P_F = f(IF_{(AV)})$ per diode; sinusoidal current waveform where $a = \text{form factor} = IF_{(RMS)} / IF_{(AV)}$.

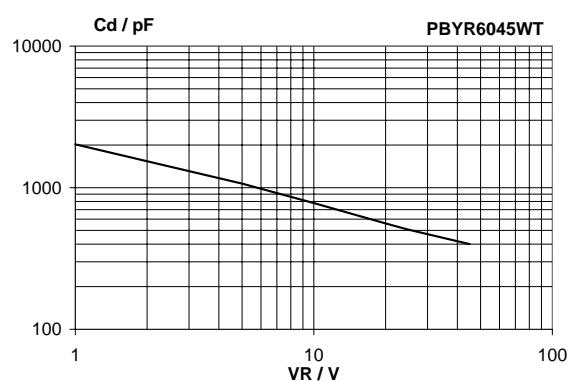


Fig.5. Typical junction capacitance per diode; $C_d = f(V_R)$; $f = 1$ MHz; $T_j = 25^\circ\text{C}$ to 125°C .

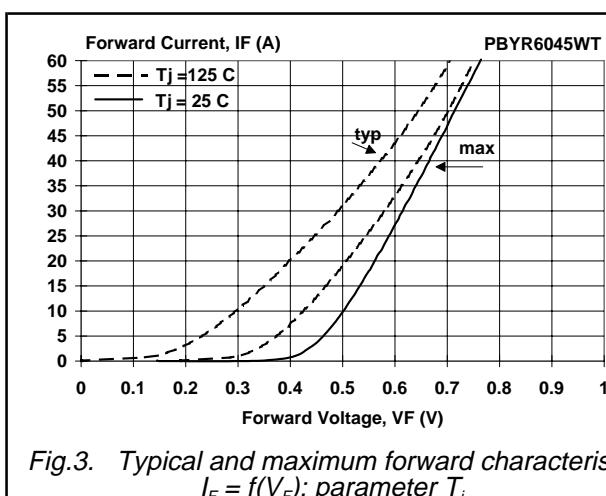


Fig.3. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

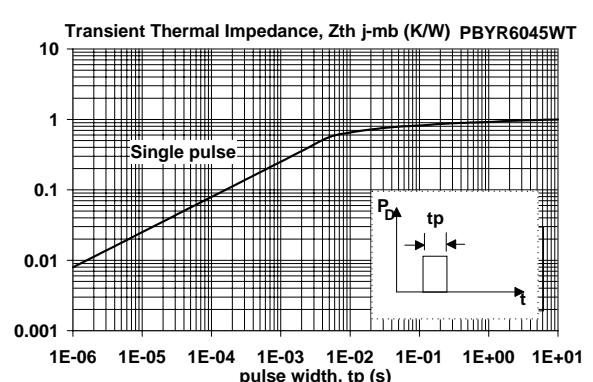


Fig.6. Transient thermal impedance per diode; $Z_{th\ j\text{-}mb} = f(t_p)$.

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MECHANICAL DATA

Dimensions in mm

Net Mass: 5 g

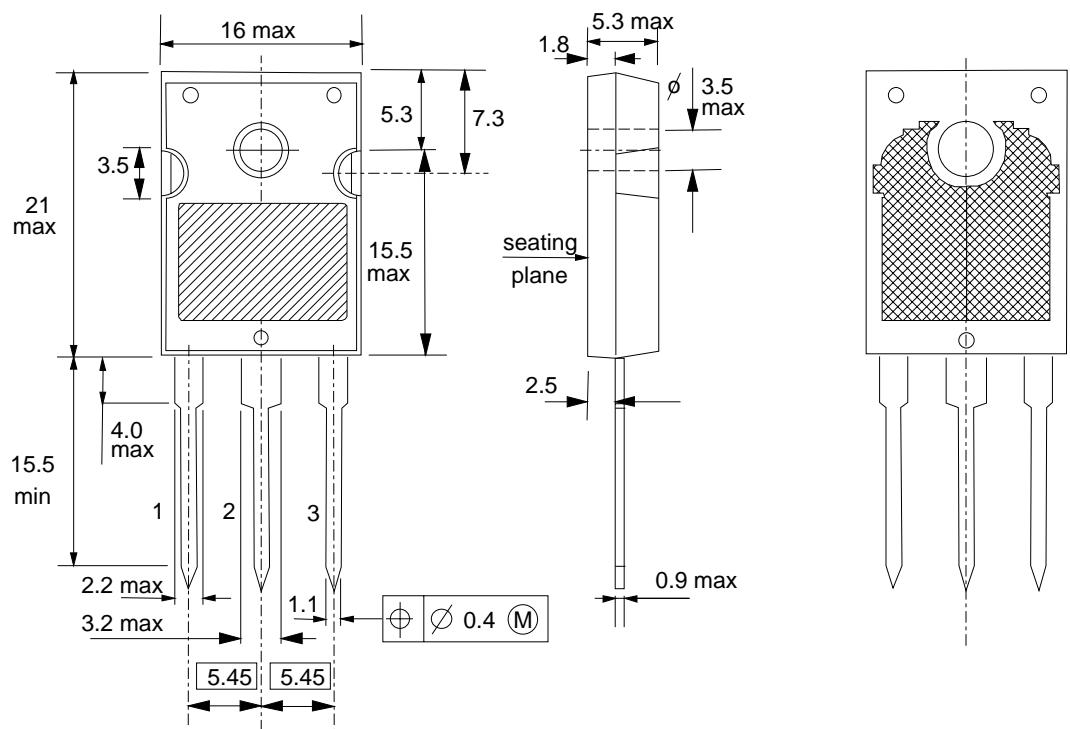


Fig.7. SOT429 (TO247); pin 2 connected to mounting base.

Notes

1. Refer to mounting instructions for SOT429 envelope.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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